

ESAD33(C, N, D)(15A) 富士小電カダイオード

高速整流ダイオード

FAST RECOVERY DIODE

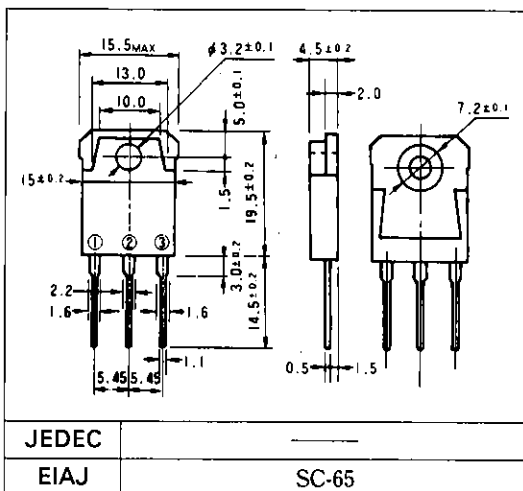
■特長：Features

- メサ形のため耐圧が高い
High voltage by mesa design.
- 高信頼性
High reliability

■用途：Applications

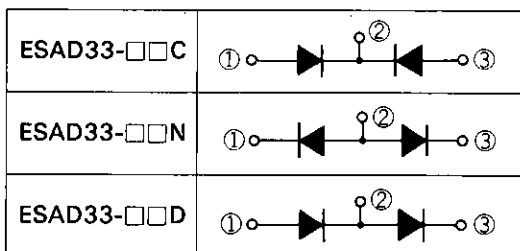
- 高速電力スイッチング
High speed power switching.

■外形寸法：Outline Drawings



■電極接続

Connection Diagram



■定格と特性：Maximum Ratings and Characteristics

●絶対最大定格：Absolute Maximum Ratings

Items	Symbols	Conditions	Ratings	Units
			-02	
ピーク繰り返し逆電圧 Repetitive Peak Reverse Voltage	V_{RRM}		200	V
ピーク非繰り返し逆電圧 Non-Repetitive Peak Reverse Voltage	V_{RSM}		220	V
平均出力電流 Average Output Current	I_o	正弦波, duty = 1/2, $T_c = 88^\circ\text{C}$ Sine wave	15*	A
サージ電流 Surge Current	I_{FSM}	正弦波 Sine wave 10ms 定格負荷状態より	80	A
接合温度 Operating Junction Temperature	T_j		-40 ~ +150	$^\circ\text{C}$
保存温度 Storage Temperature	T_{stg}		-40 ~ +150	$^\circ\text{C}$

*センタータップ平均出力電流

*average forward current of center tap full wave connection

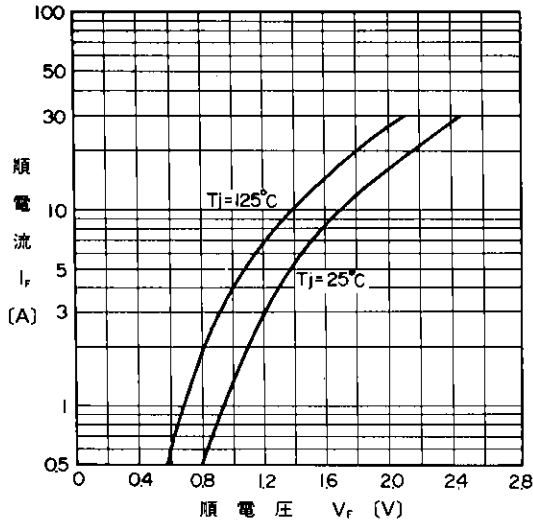
●電気的特性(特に指定がない限り周囲温度 $T_a = 25^\circ\text{C}$ とする)

Electrical Characteristics ($T_a = 25^\circ\text{C}$ Unless otherwise specified)

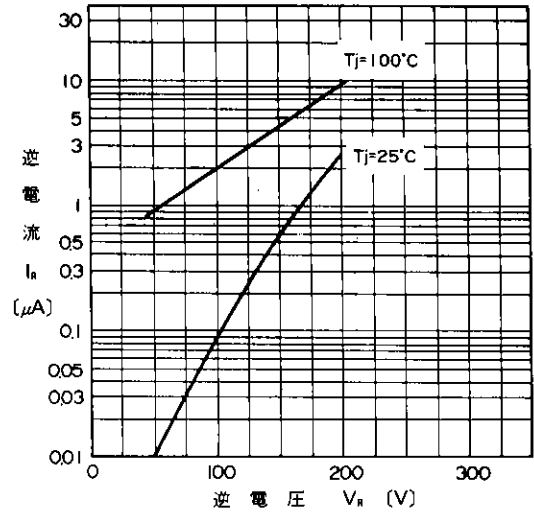
Items	Symbols	Conditions	Max.	Units
順電圧 Forward Voltage Drop	V_{FM}	$I_{FM} = 5.0\text{A}$	1.5	V
逆電流 Reverse Current	I_{RRM}	$V_R = V_{RRM}$	1.0	mA
逆回復時間 Reverse Recovery Time	t_{rr}	$I_F = 0.1\text{A}, I_R = 0.1\text{A}$	100	ns
熱抵抗 Thermal Resistance	$R_{th(j-c)}$	接合・ケース間 平滑直流 junction to case	2.0	$^\circ\text{C}/\text{W}$

■特性曲線：Characteristics

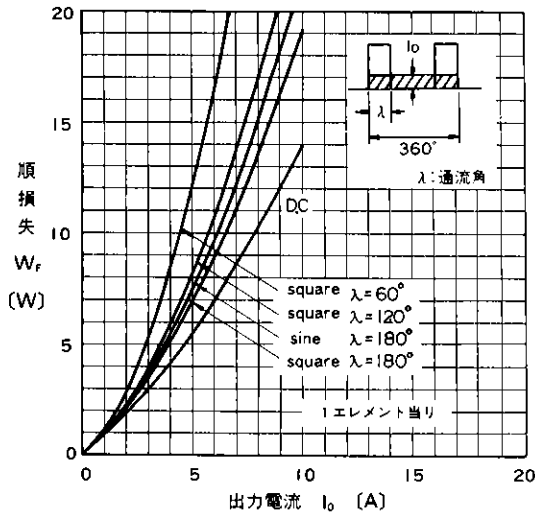
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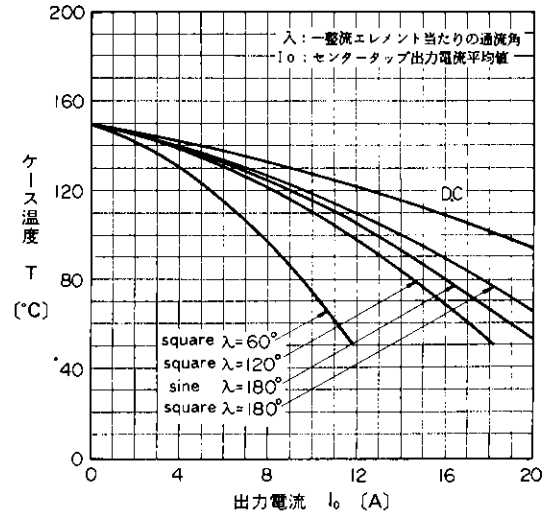
順特性 (代表特性)
Forward Characteristics



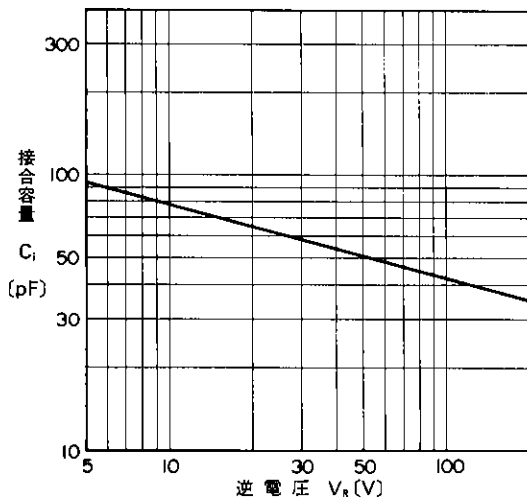
逆特性 (代表特性)
Reverse Characteristics



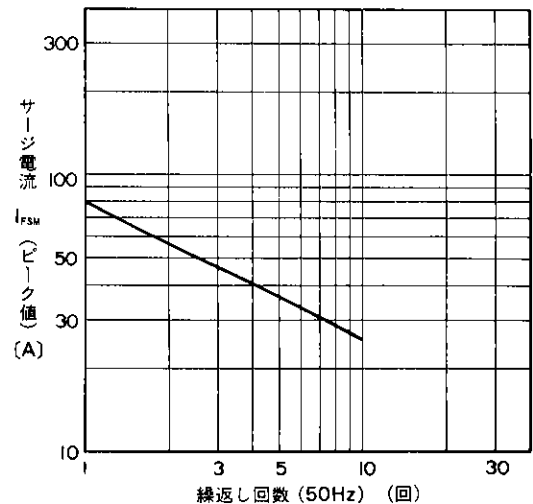
順損失特性
Forward Power Dissipation



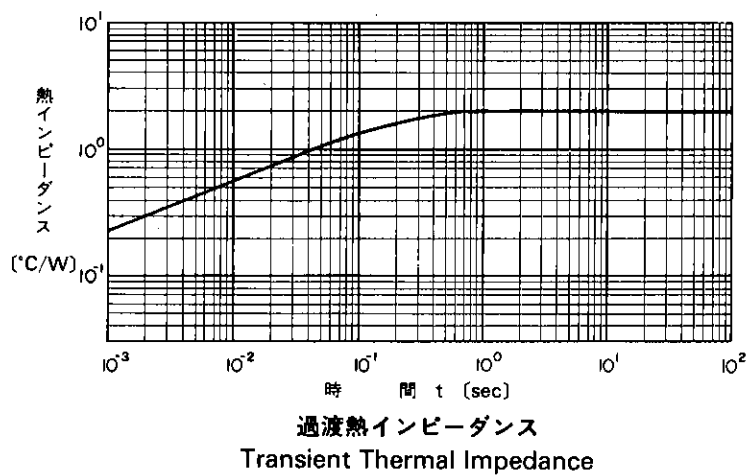
出力電流-ケース温度特性
Output Current-Case Temperature



接合容量特性(代表特性)
Junction Capacitance Characteristics



サージ電流耐量
Surge Capability



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